

**DESCRIPTION**

The FMMT591 is available in SOT-23 package.

**MECHANICAL DATA**

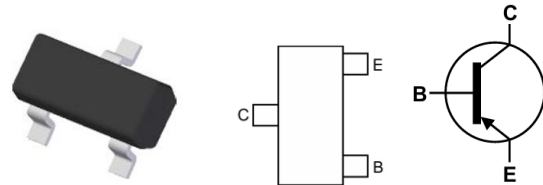
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight 0.008 grams (Approximate)

**ORDERING INFORMATION**

Package Type	Part Number
SOT-23	FMMT591
Note	SPQ:3,000pcs/Reel
AiT provides all RoHS products	

**FEATURE**

- $I_C = -1A$  High Continuous Collector Current
- $I_{CM} = -2A$  Peak Pulse Current
- $R_{CE(sat)} = 355m\Omega$  for a Low Equivalent On-Resistance
- Complementary NPN type: FMMT491

**PIN DESCRIPTION**

SOT-23

Pin#	Symbol	Function
1	B	Base
2	E	Emitter
3	C	Collector

**ABSOLUTE MAXIMUM RATINGS**

$V_{CBO}$ , Collector-Base Voltage	-80V
$V_{CEO}$ , Collector-Emitter Voltage	-60V
$V_{EBO}$ , Emitter-Base Voltage	-5V
$I_{CM}$ , Peak Pulse Current	-2A
$I_C$ , Continuous Collector Current	-1A
$I_B$ , Base Current	-200mA
$P_{TOT}$ , Power Dissipation at $T_{amb} = 25^\circ C$	500mW
$T_J$ , Operating and Storage Temperature Range	$-55^\circ C \sim +150^\circ C$
$T_{STG}$ , Operating and Storage Temperature Range	$-55^\circ C \sim +150^\circ C$

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



## ELECTRICAL CHARACTERISTICS

T<sub>A</sub> = 25°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =-100μA, I <sub>E</sub> =0	-80	-	-	V
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =-10mA, I <sub>B</sub> =0*	-60	-	-	V
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =-100μA, I <sub>C</sub> =0	-5	-	-	V
Collector Cut-Off Current	I <sub>CBO</sub>	V <sub>CB</sub> =-60V	-	-	-100	nA
Emitter Cut-Off Current	I <sub>EBO</sub>	V <sub>EB</sub> =-4V, I <sub>C</sub> =0	-	-	-100	nA
Collector- Emitter Cut-Off Current	I <sub>CES</sub>	V <sub>CES</sub> =-60V	-	-	-100	nA
Collector- Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =-500mA, I <sub>B</sub> =-50mA*	-	-	-0.3	V
		I <sub>C</sub> =-1A, I <sub>B</sub> =-100mA*	-	-	-0.6	V
Base- Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =-1A, I <sub>B</sub> =-100mA*	-	-	-1.2	V
Base- Emitter Turn-on Voltage	V <sub>BE(on)</sub>	I <sub>C</sub> =-1A, V <sub>CE</sub> =-5V*	-	-	-1.0	V
Static Forward Current Transfer Ratio	h <sub>FE</sub>	I <sub>C</sub> =-1mA, V <sub>CE</sub> =-5V*	100	-	300	
		I <sub>C</sub> =-500mA, V <sub>CE</sub> =-5V*	100	-		
		I <sub>C</sub> =-1A, V <sub>CE</sub> =-5V*	80	-		
		I <sub>C</sub> =-2A, V <sub>CE</sub> =-5V*	15	-		
Transition Frequency	f <sub>T</sub>	I <sub>C</sub> =-50mA, V <sub>CE</sub> =-10V f=100MHz	150	-	-	MHz
Output Capacitance	C <sub>obo</sub>	V <sub>CB</sub> =-10V, f=1MHz	-	-	10	pF

\*Measured under pulsed conditions. Pulse width=300μs. Duty cycle≤2%



## TYPICAL PERFORMANCE CHARACTERISTICS

Fig 1.  $V_{CE(sat)}$  vs.  $I_C$

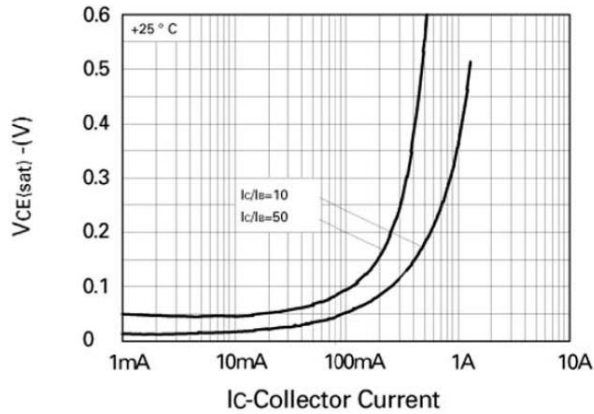


Fig 2.  $V_{CE(sat)}$  vs.  $I_C$

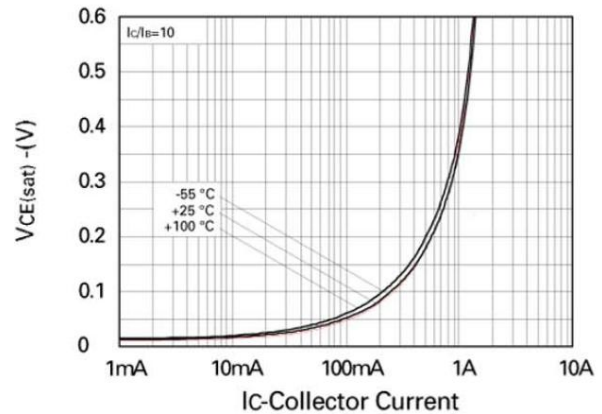


Fig3.  $h_{FE}$  vs.  $I_C$

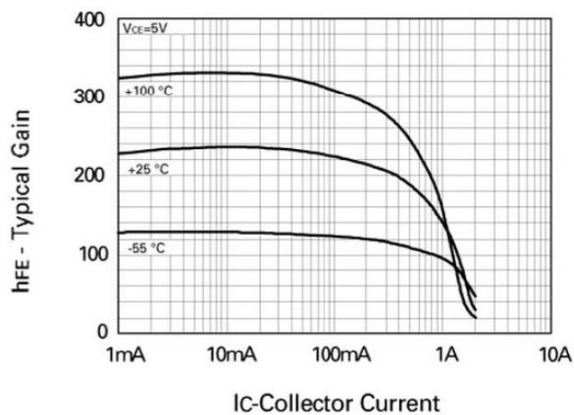


Fig4.  $V_{BE(sat)}$  vs.  $I_C$

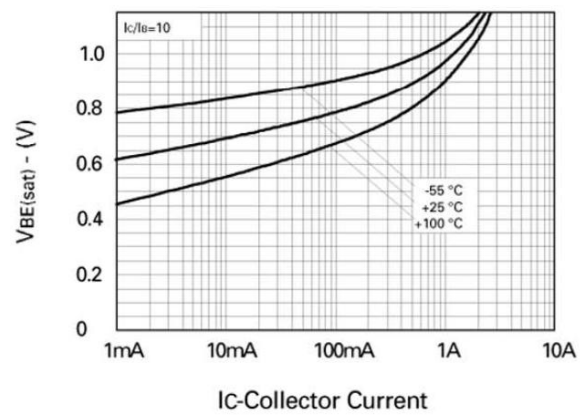


Fig5.  $V_{BE(on)}$  vs.  $I_C$

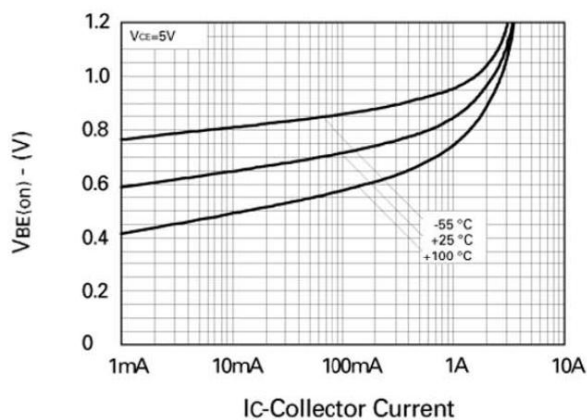
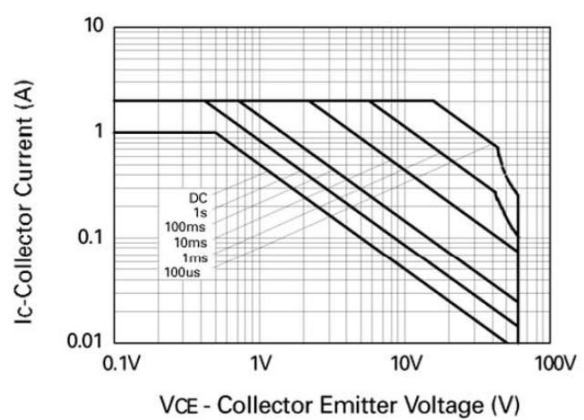


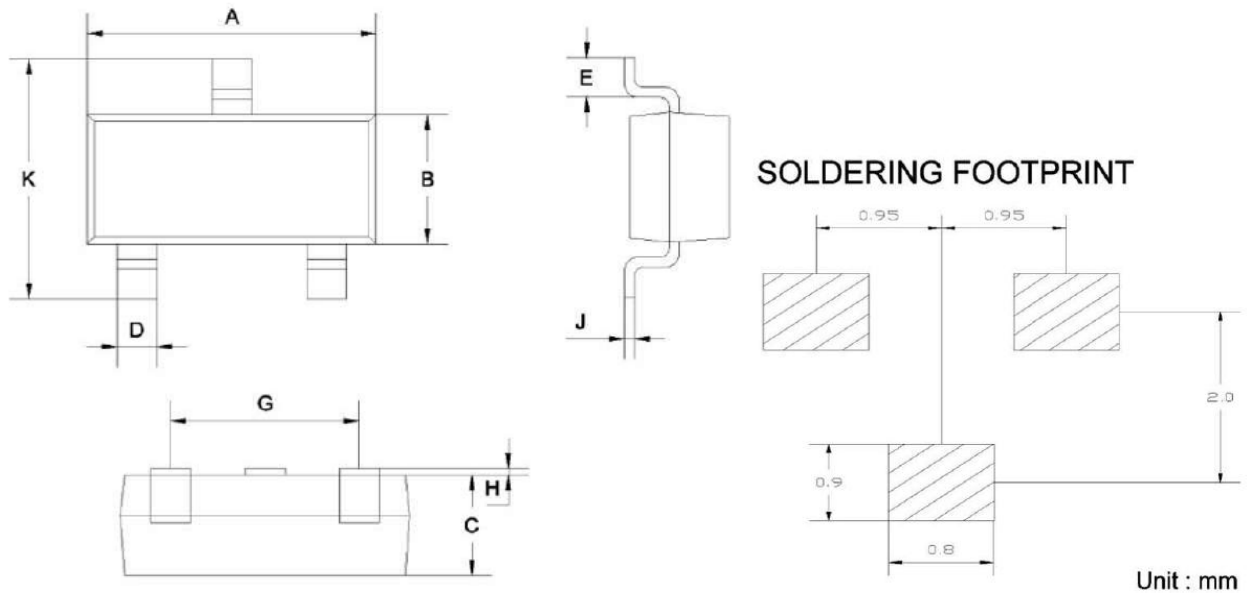
Fig6. Safe Operating Area





## PACKAGE INFORMATION

Dimension in SOT-23 (Unit: mm)



Symbol	Min	Max
A	2.85	2.95
B	1.25	1.35
C	1.0 Typical	
D	0.37	0.43
E	0.35	0.48
G	1.85	1.95
H	0.02	0.1
J	0.1 Typical	
K	2.35	2.45



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